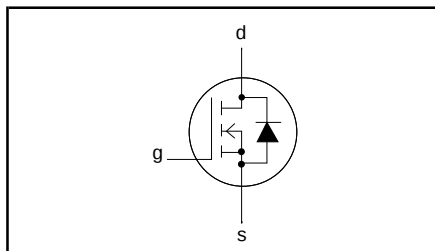


N-channel TrenchMOS™ transistor

Logic level FET

BSS123**FEATURES**

- 'Trench' technology
- Extremely fast switching
- Logic level compatible
- Subminiature surface mounting package

SYMBOL**QUICK REFERENCE DATA**

$$V_{DSS} = 100 \text{ V}$$

$$I_D = 150 \text{ mA}$$

$$R_{DS(ON)} \leq 6 \Omega (V_{GS} = 10 \text{ V})$$

GENERAL DESCRIPTION

N-channel enhancement mode field-effect transistor in a plastic envelope using 'trench' technology.

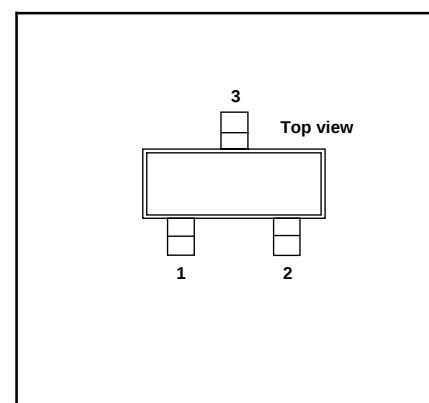
Applications:-

- Relay driver
- High-speed line driver
- Telephone ringer

The BSS123 is supplied in the SOT23 subminiature surface mounting package.

PINNING

PIN	DESCRIPTION
1	gate
2	source
3	drain

SOT23**LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DSS}	Drain-source voltage	$T_j = 25^\circ\text{C}$ to 150°C	-	100	V
V_{DGR}	Drain-gate voltage	$T_j = 25^\circ\text{C}$ to 150°C ; $R_{GS} = 20 \text{ k}\Omega$	-	100	V
V_{GS}	Gate-source voltage		-	± 20	V
I_D	Continuous drain current	$T_a = 25^\circ\text{C}$	-	150	mA
I_{DM}	Pulsed drain current	$T_a = 25^\circ\text{C}$	-	600	mA
P_D	Total power dissipation	$T_a = 25^\circ\text{C}$	-	0.25	W
T_j, T_{stg}	Operating junction and storage temperature		- 55	150	$^\circ\text{C}$

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
$R_{th\ j-a}$	Thermal resistance junction to ambient	surface mounted on FR4 board	500	-	K/W

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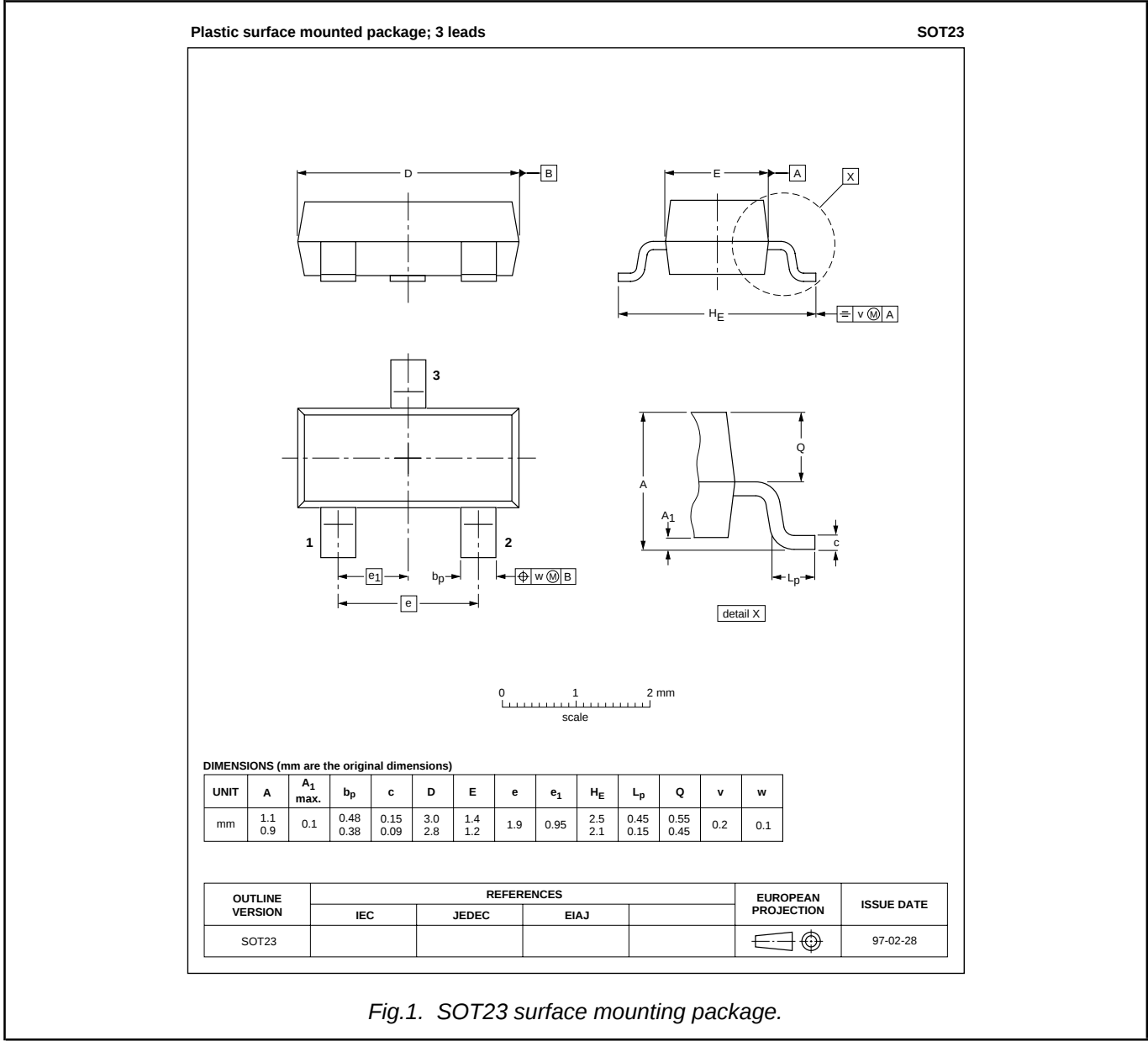
BSS123**ELECTRICAL CHARACTERISTICS** $T_J = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)DSS}$	Drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 10\text{ }\mu\text{A}$	100	130	-	V
$V_{GS(TO)}$	Gate threshold voltage	$V_{DS} = V_{GS}; I_D = 1\text{ mA}$	1	2	2.8	V
$R_{DS(ON)}$	Drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 120\text{ mA}$	-	3.5	6	Ω
g_{fs}	Forward transconductance	$V_{DS} = 25\text{ V}; I_D = 120\text{ mA}$	-	350	-	mS
I_{DSS}	Zero gate voltage drain current	$V_{DS} = 60\text{ V}; V_{GS} = 0\text{ V}$	-	10	100	nA
I_{GSS}	Gate source leakage current	$V_{GS} = \pm 20\text{ V}; V_{DS} = 0\text{ V}$	-	10	100	nA
t_{on}	Turn-on time	$V_{DD} = 50\text{ V}; R_D = 250\text{ }\Omega; V_{GS} = 10\text{ V};$ $R_G = 50\text{ }\Omega; \text{Resistive load}$	-	3	10	ns
t_{off}	Turn-off time		-	12	20	ns
C_{iss}	Input capacitance	$V_{GS} = 0\text{ V}; V_{DS} = 25\text{ V}; f = 1\text{ MHz}$	-	23	40	pF
C_{oss}	Output capacitance		-	6	25	pF
C_{rss}	Feedback capacitance		-	4	10	pF

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BSS123

MECHANICAL DATA



Notes

1. This product is supplied in anti-static packaging. The gate-source input must be protected against static discharge during transport or handling.
2. Refer to SMD Footprint Design and Soldering Guidelines, Data Handbook SC18.
3. Epoxy meets UL94 V0 at 1/8".

N-channel TrenchMOS™ transistor

Logic level FET

BSS123

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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LIFE SUPPORT APPLICATIONS

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